

IPP110N20NA

Request a Quote

IPP110N20NA Information

	Part Number	IPP110N20NA	
	Manufacturer	Infineon Technologies	
www.heiseper.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 200V 88A TO220-3	
12	Package	TO-220-3	
-		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP110N20NA Specifications

Manufacturer Part Number	IPP110N20NA
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptimWatt?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	88A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 270µA
Gate Charge (Qg) (Max) @ Vgs	87nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	7100pF @ 100V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	300W (Tc)
Rds On (Max) @ Id, Vgs	10.7 mOhm @ 88A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

IPP110N20NA Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP110N20NA Payment Methods



IPP110N20NA Shipping Methods



If you have any question about IPP110N20NA, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com